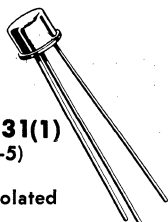


# 2N1191 thru 2N1194 (GERMANIUM)

**CASE 31(1)**  
(TO-5)

All leads isolated



PNP germanium transistors for high-gain audio amplifier and switching applications.

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{CB}$	40	Vdc
Collector-Emitter Voltage	$V_{CER}$	25	Vdc
Emitter-Base Voltage	$V_{EB}$	25	Vdc
Collector Current (Continuous)	$I_C$	200	mAdc
Storage and Operating Temperature	$T_{stg}, T_J$	-65 to +100	°C
Collector Dissipation in Ambient (Derate 2.67 mW/°C above 25°C)	$P_D$	200	mW
Thermal Resistance (Junction to Ambient)	$\theta_{JA}$	0.375	°C/mW
Thermal Resistance (Junction to Case)	$\theta_{JC}$	0.250	°C/mW

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

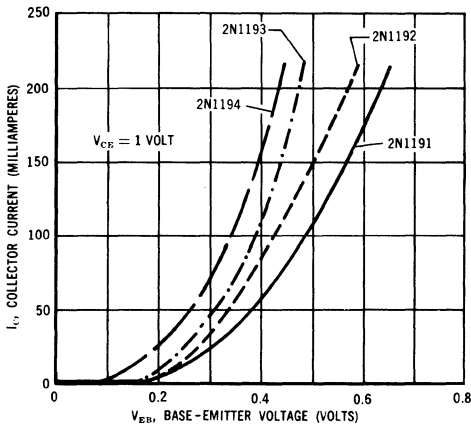
Characteristic	Symbol	Min	Typ	Max	Unit
Collector-Base Cutoff Current ( $V_{CB} = 25\text{ V}, I_E = 0$ ) ( $V_{CB} = 1.0\text{ V}, I_E = 0$ )	$I_{CBO}$	-	-	15	$\mu\text{Adc}$
Emitter-Base Cutoff Current ( $V_{EB} = 25\text{ V}, I_C = 0$ )	$I_{EBO}$	-	-	15	$\mu\text{Adc}$
Collector-Emitter Leakage Current ( $V_{CB} = 25\text{ V}, R_{BE} = 10\text{ k}\Omega$ )	$I_{CER}$	-	-	600	$\mu\text{Adc}$
Output Capacitance ( $V_{CE} = 6\text{ V}, I_E = 1.0\text{ mA}$ )	$C_{ob}$	-	20	-	pF
Noise Figure ( $V_{CE} = 4.5\text{ V}, I_E = 0.5\text{ mA}$ , $f = 1\text{ kHz}, R_s = 100\text{ ohms}$ )	NF	-	10	-	dB
Small Signal Current Gain Cutoff Frequency ( $V_{CB} = 6\text{ V}, I_E = 1.0\text{ mA}$ )	$f_{\alpha b}$	-	1.5	-	MHz
	2N1191	-	2.0	-	
	2N1192	-	2.5	-	
	2N1193	-	3.0	-	
	2N1194	-	-	-	

# 2N1191 thru 2N1194 (continued)

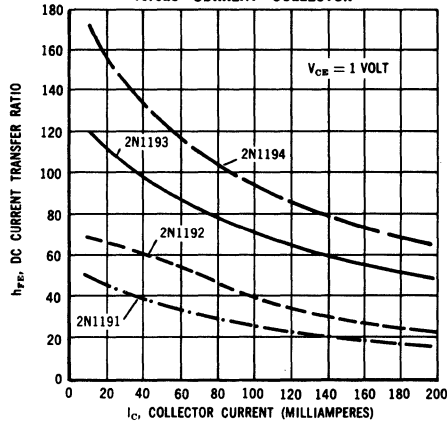
## ELECTRICAL CHARACTERISTICS (continued)

Characteristic		Symbol	Min	Typ	Max	Unit
Small Signal Current Gain ( $V_{CE} = 6\text{ V}$ , $I_E = 1.0\text{ mA}$ , $f = 1\text{ kHz}$ )	2N1191	$h_{fe}$	30	40	70	-
	2N1192		50	75	125	
	2N1193		100	160	250	
	2N1194		190	280	500	
DC Current Gain ( $V_{CE} = 1\text{ V}$ , $I_C = 10\text{ mA}$ )	2N1191	$h_{FE}$	20	-	80	-
	2N1192		40	-	135	
	2N1193		70	-	300	
	2N1194		125	-	600	
Small Signal Power Gain ( $V_{CE} = 6\text{ V}$ , $I_E = 1.0\text{ mA}$ , $f = 1\text{ kHz}$ , matched)	2N1191	$G_e$	-	42	-	dB
	2N1192		-	44	-	
	2N1193		-	46	-	
	2N1194		-	48	-	
Base-Emitter Input Voltage ( $V_{CE} = 6\text{ V}$ , $I_C = 1.0\text{ mA}$ )		$V_{BE}$	-	-	0.3	Vdc

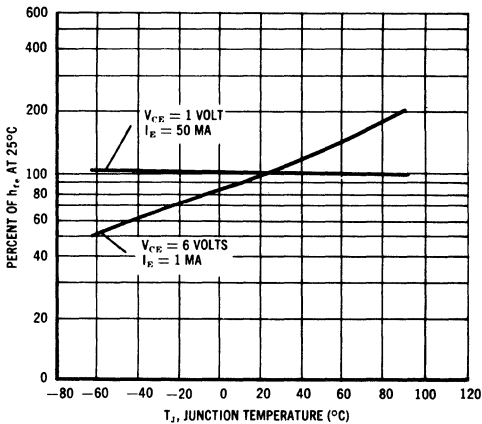
OUTPUT CURRENT versus BASE DRIVE VOLTAGE



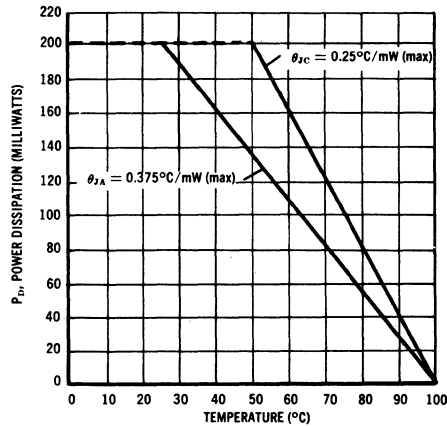
DC CURRENT TRANSFER RATIO versus CURRENT COLLECTOR



SMALL SIGNAL CURRENT GAIN versus TEMPERATURE (For All Types)



POWER-TEMPERATURE DERATING CURVE (For All Types)



# 2N1195

FOR SPECIFICATIONS, SEE 2N1141 DATA.